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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	250
Number of Logic Elements/Cells	2000
Total RAM Bits	81920
Number of I/O	37
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	49-VFBGA
Supplier Device Package	49-UCBGA (3x3)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/ice40lm2k-cm49tr1k

General Description

iCE40LM family is an ultra-low power FPGA and sensor manager designed for ultra-low power mobile applications, such as smartphones, tablets and hand-held devices. The iCE40LM family includes integrated SPI & I²C blocks to interface with virtually all mobile sensors and application processors. The iCE40LM family also features two Strobe Generators that can generate strobes in Microsecond ranges with the Low-Power Strobe Generator, and also generates strobes in Nanosecond ranges with the High-Speed Strobe Generator.

In addition, the iCE40LM family of devices includes logic to perform other functions such as mobile bridging, antenna tuning, GPIO expansion, motion/gesture recognition, IR remote control, bar code emulation and other custom functions.

The iCE40LM family features three device densities, from 1100 to 3520 Look Up Tables (LUTs) of logic with programmable I/Os that can be used as either SPI/I²C interface ports or general purpose I/O's. It also has up to 80 kbits of Block RAMs to work with user logic.

Features

- **Flexible Logic Architecture**
 - Three devices with 1100 to 3520 LUTs
 - 18 I/O pins for 25-pin WLCSP
- **Ultra-low Power Devices**
 - Advanced 40 nm ultra-low power process
 - As low as 120 μ W standby power typical
- **Embedded and Distributed Memory**
 - Up to 80 kbits sysMEM™ Embedded Block RAM
- **Two Hardened I²C Interfaces**
- **Two Hardened SPI Interfaces**
- **Two On-Chip Strobe Generators**
 - Low-Power Strobe Generator (Microsecond ranges)
 - High-Speed Strobe Generator (Nanosecond ranges)
- **High Current Drive Outputs for LED**
 - Three High Drive (HD) output in each device
 - Source/sink nominal 24 mA
- **Flexible On-Chip Clocking**
 - Six low-skew global signal resource
- **Flexible Device Configuration**
 - SRAM is configured through SPI
- **Ultra-Small Form Factor**
 - As small as 25-pin WLCSP package 1.71 mm x 1.71 mm

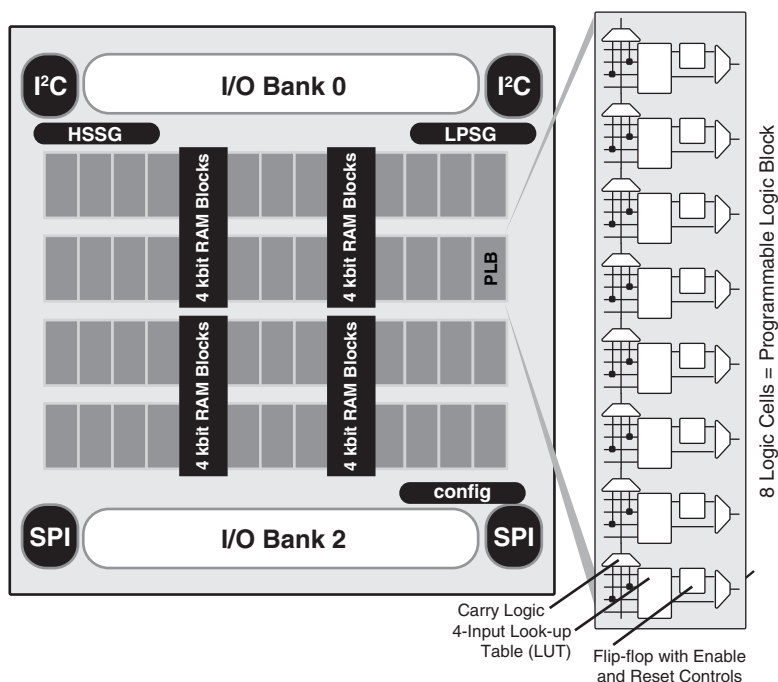
Applications

- Smartphones
- Tablets and Consumer Handheld Devices
- Handheld Commercial and Industrial Devices
- Multi Sensor Management Applications
- Sensor Pre-processing & Sensor Fusion
- Always-On Sensor Applications

Architecture Overview

The iCE40LM family architecture contains an array of Programmable Logic Blocks (PLB), two Strobe Generators, two user configurable I²C controllers, two user configurable SPI controllers, and blocks of sysMEM™ Embedded Block RAM (EBR) surrounded by Programmable I/O (PIO). Figure 2-1 shows the block diagram of the iCE40LM-4K device.

Figure 2-1. iCE40LM-4K Device, Top View



The logic blocks, Programmable Logic Blocks (PLB) and sysMEM EBR blocks, are arranged in a two-dimensional grid with rows and columns. Each column has either logic blocks or EBR blocks. The PIO cells are located at the top and bottom of the device, arranged in banks. The PLB contains the building blocks for logic, arithmetic, and register functions. The PIOs utilize a flexible I/O buffer referred to as a sysIO buffer that supports operation with a variety of interface standards. The blocks are connected with many vertical and horizontal routing channel resources. The place and route software tool automatically allocates these routing resources.

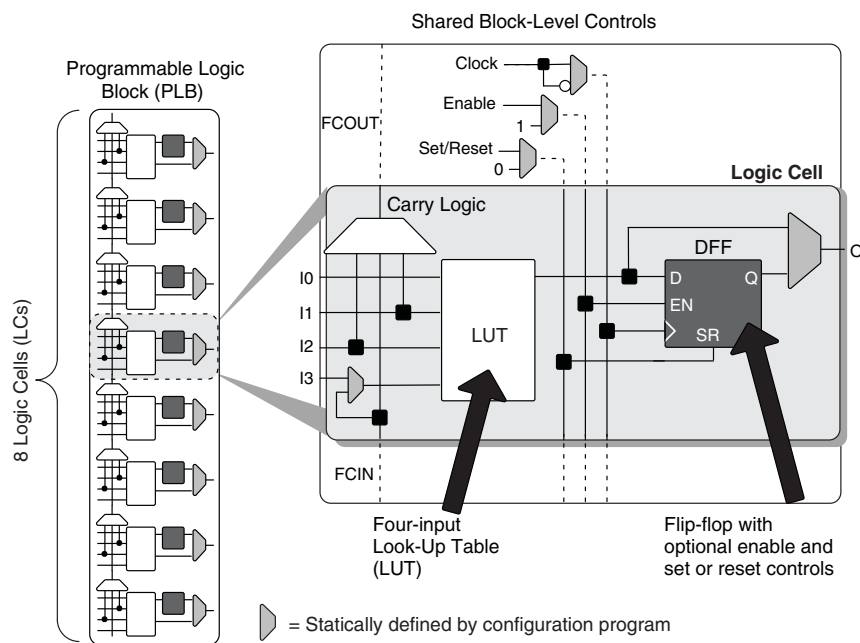
In the iCE40LM family, There are two sysIO banks, one on top and one on bottom. User can connect both V_{CCIO} s together, if all the I/Os are using the same voltage standard. Refer to the details in later sections of this document. The sysMEM EBRs are large 4 kbit, dedicated fast memory blocks. These blocks can be configured as RAM, ROM or FIFO with user logic using PLBs.

Every device in the family has two user SPI ports, one of these (right side) SPI port also supports programming and configuration of the device. The iCE40LM also includes two user I²C ports, and two Strobe Generators.

PLB Blocks

The core of the iCE40LM device consists of Programmable Logic Blocks (PLB) which can be programmed to perform logic and arithmetic functions. Each PLB consists of eight interconnected Logic Cells (LC) as shown in Figure 2-2. Each LC contains one LUT and one register.

Figure 2-2. PLB Block Diagram



Logic Cells

Each Logic Cell includes three primary logic elements shown in Figure 2-2.

- A four-input Look-Up Table (LUT) builds any combinational logic function, of any complexity, requiring up to four inputs. Similarly, the LUT element behaves as a 16x1 Read-Only Memory (ROM). Combine and cascade multiple LUTs to create wider logic functions.
- A 'D'-style Flip-Flop (DFF), with an optional clock-enable and reset control input, builds sequential logic functions. Each DFF also connects to a global reset signal that is automatically asserted immediately following device configuration.
- Carry Logic boosts the logic efficiency and performance of arithmetic functions, including adders, subtracters, comparators, binary counters and some wide, cascaded logic functions.

Table 2-1. Logic Cell Signal Descriptions

Function	Type	Signal Names	Description
Input	Data signal	I0, I1, I2, I3	Inputs to LUT
Input	Control signal	Enable	Clock enable shared by all LCs in the PLB
Input	Control signal	Set/Reset ¹	Asynchronous or synchronous local set/reset shared by all LCs in the PLB.
Input	Control signal	Clock	Clock one of the eight Global Buffers, or from the general-purpose interconnects fabric shared by all LCs in the PLB
Input	Inter-PLB signal	FCIN	Fast carry in
Output	Data signals	O	LUT or registered output
Output	Inter-PFU signal	FCOUT	Fast carry out

1. If Set/Reset is not used, then the flip-flop is never set/reset, except when cleared immediately after configuration.

sysCLOCK Phase Locked Loops (PLLs) - *NOT SUPPORTED on the 25-Pin WLCSP*

The sysCLOCK PLLs provide the ability to synthesize clock frequencies. The iCE40LM devices have one sysCLOCK PLL (Please note that the 25-pin WLCSP package does not support the PLL). REFERENCECLK is the reference frequency input to the PLL and its source can come from an external I/O pin, the internal strobe generator or from internal routing. EXTFEEDBACK is the feedback signal to the PLL which can come from internal routing or an external I/O pin. The feedback divider is used to multiply the reference frequency and thus synthesize a higher frequency clock output.

The PLLOUT output has an output divider, thus allowing the PLL to generate different frequencies for each output. The output divider can have a value from 1 to 64 (in increments of 2X). The PLLOUT outputs can all be used to drive the iCE40 global clock network directly or general purpose routing resources can be used.

The LOCK signal is asserted when the PLL determines it has achieved lock and de-asserted if a loss of lock is detected. A block diagram of the PLL is shown in Figure 2-3.

The timing of the device registers can be optimized by programming a phase shift into the PLLOUT output clock which will advance or delay the output clock with reference to the REFERENCECLK clock. This phase shift can be either programmed during configuration or can be adjusted dynamically. In dynamic mode, the PLL may lose lock after a phase adjustment on the output used as the feedback source and not relock until the tLOCK parameter has been satisfied.

The iCE40LM PLL functions the same as the PLLs in the iCE40 family. For more details on the PLL, see TN1251, [iCE40 sysCLOCK PLL Design and Usage Guide](#).

Figure 2-3. PLL Diagram

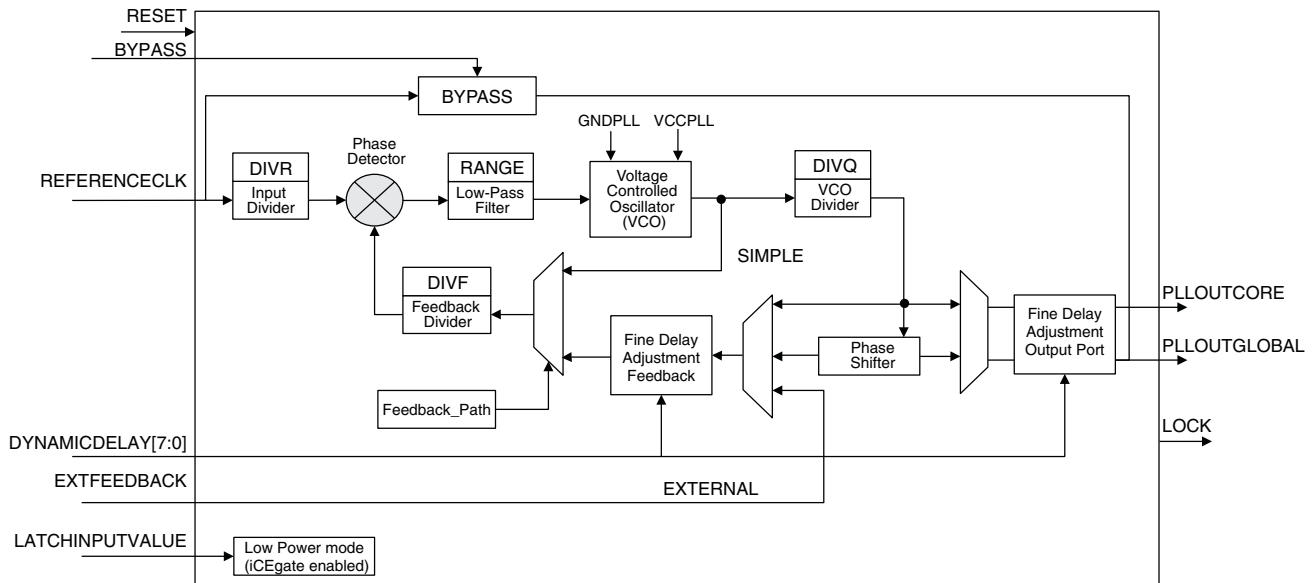


Table 2-3 provides signal descriptions of the PLL block.

RAM Initialization and ROM Operation

If desired, the contents of the RAM can be pre-loaded during device configuration.

By preloading the RAM block during the chip configuration cycle and disabling the write controls, the sysMEM block can also be utilized as a ROM.

Memory Cascading

Larger and deeper blocks of RAM can be created using multiple EBR sysMEM Blocks.

RAM4k Block

Figure 2-4 shows the 256x16 memory configurations and their input/output names. In all the sysMEM RAM modes, the input data and addresses for the ports are registered at the input of the memory array.

Figure 2-4. sysMEM Memory Primitives

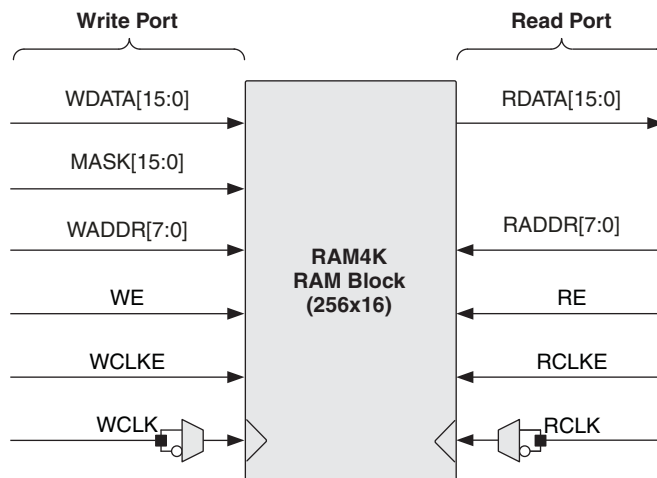


Table 2-5. EBR Signal Descriptions

Signal Name	Direction	Description
WDATA[15:0]	Input	Write Data input.
MASK[15:0]	Input	Masks write operations for individual data bit-lines. 0 = write bit; 1 = don't write bit
WADDR[7:0]	Input	Write Address input. Selects one of 256 possible RAM locations.
WE	Input	Write Enable input.
WCLKE	Input	Write Clock Enable input.
WCLK	Input	Write Clock input. Default rising-edge, but with falling-edge option.
RDATA[15:0]	Output	Read Data output.
RADDR[7:0]	Input	Read Address input. Selects one of 256 possible RAM locations.
RE	Input	Read Enable input.
RCLKE	Input	Read Clock Enable input.
RCLK	Input	Read Clock input. Default rising-edge, but with falling-edge option.

The iCE40LM EBR block functions the same as EBR blocks in the iCE40 family. For further information on the sysMEM EBR block, please refer to TN1250, [Memory Usage Guide for iCE40 Devices](#).

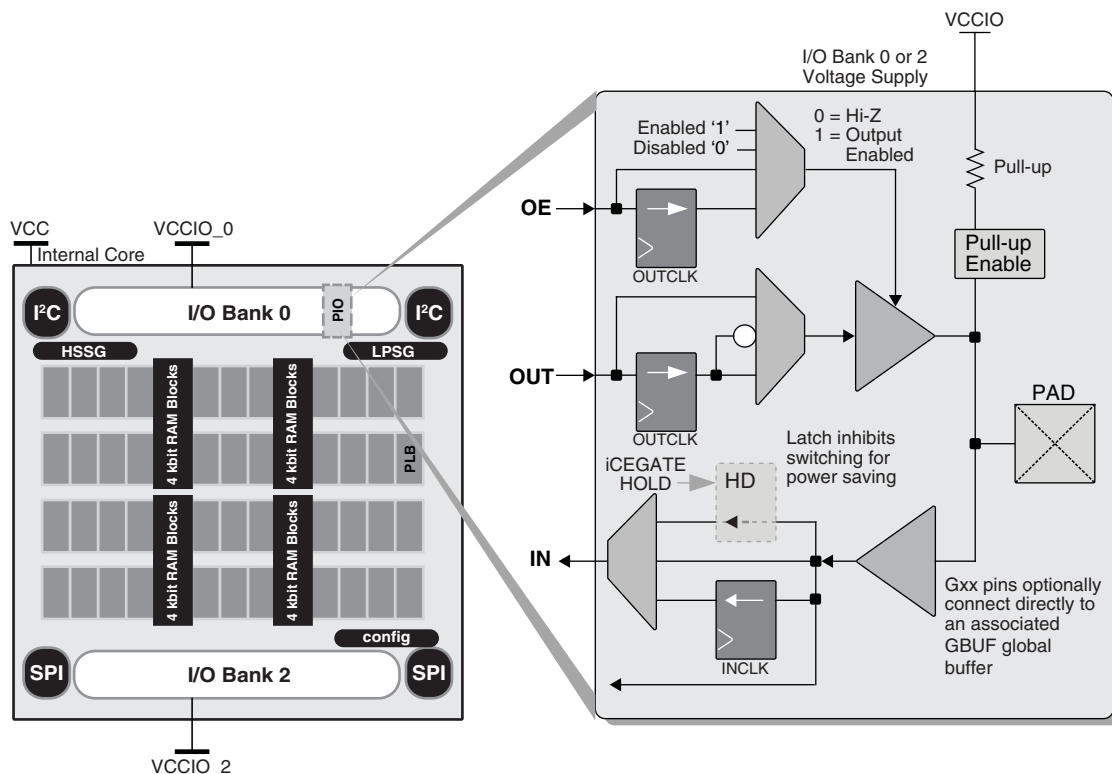
sysIO Buffer Banks

iCE40LM devices have up to two I/O banks with independent V_{CCIO} rails. Configuration bank V_{CC_SPI} for the SPI I/Os is connected to V_{CCIO2} on the 25-pin WLCSP package.

Programmable I/O (PIO)

The programmable logic associated with an I/O is called a PIO. The individual PIOs are connected to their respective sysIO buffers and pads. The PIOs are placed on the top and bottom of the devices.

Figure 2-5. I/O Bank and Programmable I/O Cell



The PIO contains three blocks: an input register block, output register block iCEGate™ and tri-state register block. To save power, the optional iCEGate™ latch can selectively freeze the state of individual, non-registered inputs within an I/O bank. Note that the freeze signal is common to the bank. These blocks can operate in a variety of modes along with the necessary clock and selection logic.

Input Register Block

The input register blocks for the PIOs on all edges contain registers that can be used to condition high-speed interface signals before they are passed to the device core.

Output Register Block

The output register block can optionally register signals from the core of the device before they are passed to the sysIO buffers.

Figure 2-6 shows the input/output register block for the PIOs.

Figure 2-6. iCE I/O Register Block Diagram

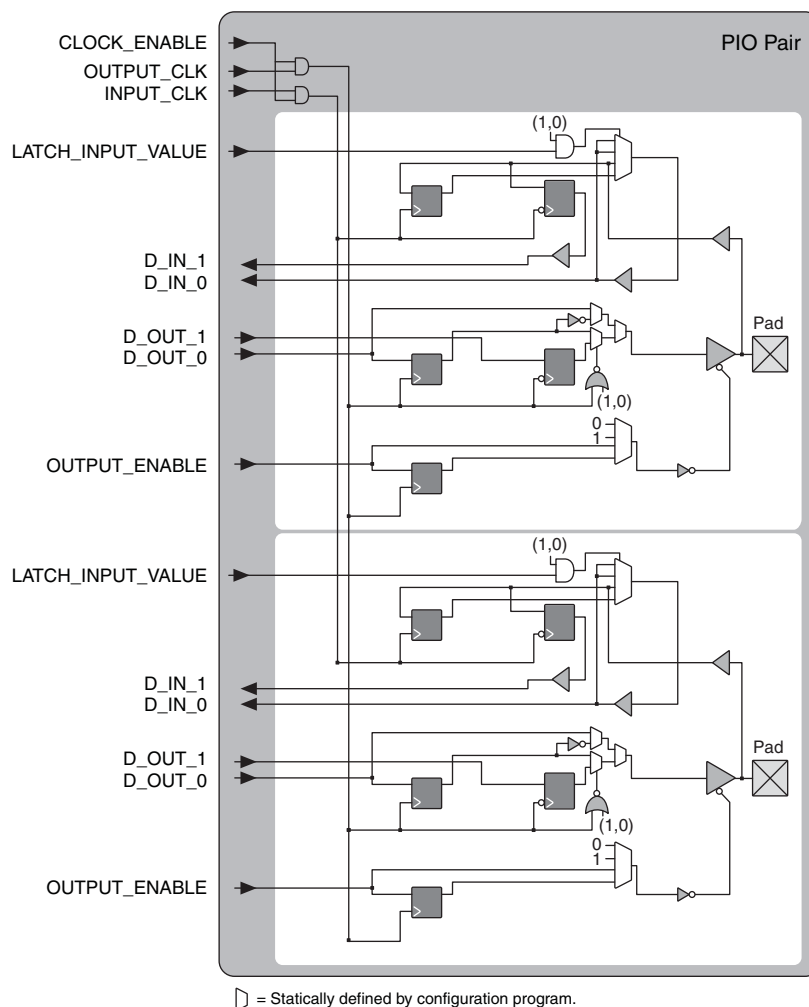


Table 2-6. PIO Signal List

Pin Name	I/O Type	Description
OUTPUT_CLK	Input	Output register clock
CLOCK_ENABLE	Input	Clock enable
INPUT_CLK	Input	Input register clock
OUTPUT_ENABLE	Input	Output enable
D_OUT_0/1	Input	Data from the core
D_IN_0/1	Output	Data to the core
LATCH_INPUT_VALUE	Input	Latches/holds the Input Value

sysIO Buffer

Each I/O is associated with a flexible buffer referred to as a sysIO buffer. These buffers are arranged around the periphery of the device in groups referred to as banks. The sysIO buffers allow users to implement a wide variety of standards that are found in today's systems with LVCMOS interfaces.

User I²C IP

The iCE40LM devices have two I²C IP cores. Either of the two cores can be configured either as an I²C master or as an I²C slave. Both I²C cores have preassigned pins, or user can select different pins, when the core is used.

When the IP core is configured as master, it will be able to control other devices on the I²C bus through the pre-assigned pin interface. When the core is configured as the slave, the device will be able to provide I/O expansion to an I²C Master. The I²C cores support the following functionality:

- Master and Slave operation
- 7-bit and 10-bit addressing
- Multi-master arbitration support
- Clock stretching
- Up to 400 kHz data transfer speed
- General Call support

For further information on the User I²C, please refer to TN1274, [iCE40 I2C and SPI Hardened IP Usage Guide](#).

User SPI IP

The iCE40LM devices have two SPI IP cores. Both SPI cores have preassigned pins, or user can select different pins, when the SPI core is used. Both SPI IP core can be configured as a SPI master or as a slave. When the SPI IP core is configured as a master, it controls the other SPI enabled devices connected to the SPI Bus. When SPI IP core is configured as a slave, the device will be able to interface to an external SPI master.

The SPI IP core supports the following functions:

- Configurable Master and Slave modes
- Full-Duplex data transfer
- Mode fault error flag with CPU interrupt capability
- Double-buffered data register
- Serial clock with programmable polarity and phase
- LSB First or MSB First Data Transfer

For further information on the User SPI, please refer to TN1274, [iCE40 I2C and SPI Hardened IP Usage Guide](#).

High Drive I/O Pins

The iCE40LM family devices offer 3 High Drive (HD) outputs in each device in the family. The HD outputs are ideal to drive LED signals on mobile application.

These HD outputs can be driven in different drive modes. The default is standard drive, which source/sink 8mA current nominally. When HD drive option is selected, these HD outputs can source/sink 24mA current nominally.

The pins on the HD I/Os are labeled with HD in it.

Power On Reset

iCE40LM devices have power-on reset circuitry to monitor V_{CC} , V_{CCIO_0} , V_{CCIO_2} and V_{CC_SPI} voltage levels during power-up and operation. At power-up, the POR circuitry monitors these voltage levels. It then triggers download from the external Flash memory after reaching the power-up levels specified in the Power-On-Reset Voltage table in the DC and Switching Characteristics section of this data sheet. Before and during configuration, the I/Os are held in tri-state. I/Os are released to user functionality once the device has finished configuration.

iCE40LM Configuration

This section describes the programming and configuration of the iCE40LM family.

Device Configuration

There are various ways to configure the Configuration RAM (CRAM) including:

- From a SPI Flash (Master SPI mode)
- System microprocessor to drive a Serial Slave SPI port (SSPI mode)

For more details on configuring the iCE40LM, please see TN1248, [iCE40 Programming and Configuration](#).

Power Saving Options

The iCE40LM devices feature iCEGate and PLL low power mode to allow users to meet the static and dynamic power requirements of their applications. Table 2-9 describes the function of these features.

Table 2-9. iCE40LM Power Saving Features Description

Device Subsystem	Feature Description
PLL	When LATCHINPUTVALUE is enabled, forces the PLL into low-power mode; PLL output held static at last input clock value.
iCEGate	To save power, the optional iCEGate latch can selectively freeze the state of individual, non-registered inputs within an I/O bank. Registered inputs are effectively frozen by their associated clock or clock-enable control.

Absolute Maximum Ratings^{1, 2, 3}

Supply Voltage V_{CC}	–0.5 V to 1.42 V
Output Supply Voltage V_{CCIO} and V_{CC_SPI}	–0.5 V to 3.60 V
PLL Power Supply, V_{CCPLL}	–0.5 V to 1.3 V
I/O Tri-state Voltage Applied	–0.5 V to 3.60 V
Dedicated Input Voltage Applied	–0.5 V to 3.60 V
Storage Temperature (Ambient)	–65 °C to 150 °C
Junction Temperature (T_J)	–55 °C to 125 °C

1. Stress above those listed under the “Absolute Maximum Ratings” may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
2. Compliance with the Lattice [Thermal Management](#) document is required.
3. All voltages referenced to GND.

Recommended Operating Conditions¹

Symbol	Parameter		Min.	Max.	Units
V _{CC} ¹	Core Supply Voltage		1.14	1.26	V
V _{CCIO} ^{1, 2, 3}	I/O Driver Supply Voltage	V _{CCIO_0} , V _{CCIO_2}	1.71	3.46	V
V _{CCPLL} ⁴	PLL Power Supply Voltage		1.14	1.26	V
V _{CC_SPI} ⁵	Config SPI port Power Supply Voltage		1.71	3.46	V
t _{JIND}	Junction Temperature Industrial Operation		−40	100	°C

1. Like power supplies must be tied together. V_{CCIO_0} to V_{CCIO_2} if they are at same supply voltage and if they meet the power up sequence requirement. Please refer to [Power Up Sequence](#) section. V_{CC} and V_{CCPLL} are not recommended to be tied together. Please refer to TN1252, [iCE40 Hardware Checklist](#).
2. See recommended voltages by I/O standard in subsequent table.
3. V_{CCIO} pins of unused I/O banks should be connected to the V_{CC} power supply on boards.
4. For 25-pin WLCSP, PLL is not supported.
5. For 25-pin WLCSP and 36-pin ucBGA packages, V_{CC_SPI} is connected to V_{CCIO_2} on the package. V_{CC_SPI} is used to power the SPI1 ports in both configuration mode and user mode.

Power Supply Ramp Rates^{1, 2}

Symbol	Parameter	Min.	Max.	Units
t_{RAMP}	Power supply ramp rates for all power supplies.	0.01	10	V/ms

1. Assumes monotonic ramp rates.
2. Power up sequence must be followed. Please refer to [Power Up Sequence](#) section.

Supply Current ^{1, 2, 3, 4}

Symbol	Parameter	Typ. VCC ⁴	Units
I _{CCSTDBY}	Core Power Supply Static Current	100	uA
I _{CCPLLSTDBY}	PLL Power Supply Static Current	11	uA
I _{CCIOSTDBY} , I _{CC_SPISTDBY}	V _{CCIO} , V _{CC_SPI} Power Supply Static Current	2.5	uA
I _{CCPEAK}	Core Power Supply Startup Peak Current	11.2	mA
I _{CCPLLPEAK}	PLL Power Supply Startup Peak Current	2.8	mA
I _{CCIOPEAK} , I _{CC_SPIPEAK}	V _{CCIO} , V _{CC_SPI} Power Supply Startup Peak Current	21.4	mA

- Assumes blank pattern with the following characteristics: all outputs are tri-stated, all inputs are configured as LVCMOS and held at V_{CCIO} or GND, on-chip PLL is off. For more detail with your specific design, use the Power Calculator tool. Power specified with master SPI configuration mode. Other modes may be up to 25% higher.
- Frequency = 0 MHz.
- T_J = 25 °C, power supplies at nominal voltage.
- Does not include pull-up.
- For 25-pin WLCSP, V_{CCPLL} is tied internally on the package, and V_{CC_SPI} is also connected to V_{CCIO_2} on the package.

User I²C Specifications

Parameter Symbol	Parameter Description	spec (STD Mode)			spec (FAST Mode)			Units
		Min	Typ	Max	Min	Typ	Max	
f _{SCL}	Maximum SCL clock frequency	—	—	100	—	—	400	kHz
t _{HI}	SCL clock HIGH Time	4	—	—	0.6	—	—	μs
t _{LO}	SCL clock LOW Time	4.7	—	—	1.3	—	—	μs
t _{SU,DAT}	Setup time (DATA)	250	—	—	100	—	—	ns
t _{HD,DAT}	Hold time (DATA)	0	—	—	0	—	—	ns
t _{SU,STA}	Setup time (START condition)	4.7	—	—	0.6	—	—	μs
t _{HD,STA}	Hold time (START condition)	4	—	—	0.6	—	—	μs
t _{SU,STO}	Setup time (STOP condition)	4	—	—	0.6	—	—	μs
t _{BUF}	Bus free time between STOP and START	4.7	—	—	1.3	—	—	μs
t _{CO,DAT}	SCL LOW to DATAOUT valid	—	—	3.4	—	—	0.9	μs

User SPI Specifications

Parameter Symbol	Parameter Description	Min	Typ	Max	Units
f _{MAX}	Maximum SCK clock frequency	—	—	45	MHz
t _{HI}	HIGH period of SCK clock	9	—	—	ns
t _{LO}	LOW period of SCK clock	9	—	—	ns
t _{SUmaster}	Setup time (master mode)	2	—	—	ns
t _{HOLDmaster}	Hold time (master mode)	5	—	—	ns
t _{SUslave}	Setup time (slave mode)	2	—	—	ns
t _{HOLDslave}	Hold time (slave mode)	5	—	—	ns
t _{SCK2OUT}	SCK to out (slave mode)	—	—	13.5	ns

iCE40LM External Switching Characteristics

Over Recommended Commercial Operating Conditions

Parameter	Description	Device			Units
Clocks					
Global Clocks					
f _{MAX_GBUF}	Frequency for Global Buffer Clock network	All devices		185	MHz
t _{W_GBUF}	Clock Pulse Width for Global Buffer	All devices	2	—	ns
t _{SKEW_GBUF}	Global Buffer Clock Skew Within a Device	All devices	—	650	ps
Pin-LUT-Pin Propagation Delay					
t _{PD}	Best case propagation delay through one LUT logic	All devices	—	9.1	ns
General I/O Pin Parameters (Using Global Buffer Clock without PLL)¹					
t _{SKEW_IO}	Data bus skew across a bank of IOs	All devices	—	450	ps
t _{CO}	Clock to Output - PIO Output Register	All devices	—	11.5	ns
t _{SU}	Clock to Data Setup - PIO Input Register	All devices	−0.23	—	ns
t _H	Clock to Data Hold - PIO Input Register	All devices	5.55	—	ns
1. 25-pin WLCSP package does not support PLL.					

SPI Master Configuration Time¹

Symbol	Parameter	Conditions	Max.	Units
t _{CONFIG}	POR/CRESET_B to Device I/O Active	All devices - Low Frequency (Default)	95	ms
		All devices - Medium frequency	35	ms
		All devices - High frequency	18	ms

1. Assumes sysMEM Block is initialized to an all zero pattern if they are used.

sysCONFIG Port Timing Specifications

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
All Configuration Modes						
t _{CRESET_B}	Minimum CRESET_B LOW pulse width required to restart configuration, from falling edge to rising edge		200	—	—	ns
t _{DONE_IO}	Number of configuration clock cycles after CDONE goes HIGH before the PIO pins are activated		49	—	—	Cycles
Slave SPI						
t _{CR_SCK}	Minimum time from a rising edge on CRESET_B until the first SPI WRITE operation, first SPI_XCK clock. During this time, the iCE40LM device is clearing its internal configuration memory		1200	—	—	μs
f _{MAX}	CCLK clock frequency	Write	1	—	25	MHz
		Read ¹	—	15	—	MHz
t _{CCLKH}	CCLK clock pulsewidth HIGH		20	—	—	ns
t _{CCLKL}	CCLK clock pulsewidth LOW		20	—	—	ns
t _{TSU}	CCLK setup time		12	—	—	ns
t _{STH}	CCLK hold time		12	—	—	ns
t _{STCO}	CCLK falling edge to valid output		13	—	—	ns
Master SPI						
f _{MCLK}	MCLK clock frequency	Low Frequency (Default)	6.5		13	MHz
		Medium Frequency	19.5		38	MHz
		High Frequency	33		66	MHz
t _{MCLK}	CRESET_B HIGH to first MCLK edge		1200	—	—	μs

1. Supported with 1.2 V Vcc and at 25 °C.

Switching Test Conditions

Figure 3-1 shows the output test load used for AC testing. The specific values for resistance, capacitance, voltage, and other test conditions are shown in Table 3-1.

Figure 3-1. Output Test Load, LVCMOS Standards

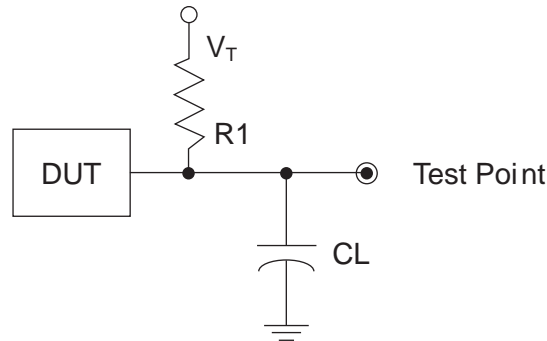


Table 3-1. Test Fixture Required Components, Non-Terminated Interfaces

Test Condition	R_1	C_L	Timing Reference	V_T
LVCMOS settings (L -> H, H -> L)	∞	0 pF	LVCMOS 3.3 = 1.5 V	—
			LVCMOS 2.5 = $V_{CCIO}/2$	—
			LVCMOS 1.8 = $V_{CCIO}/2$	—
LVCMOS 3.3 (Z -> H)	188	0 pF	1.5	V_{OL}
LVCMOS 3.3 (Z -> L)			1.5	V_{OH}
Other LVCMOS (Z -> H)			$V_{CCIO}/2$	V_{OL}
Other LVCMOS (Z -> L)			$V_{CCIO}/2$	V_{OH}
LVCMOS (H -> Z)			$V_{OH} - 0.15$	V_{OL}
LVCMOS (L -> Z)			$V_{OL} - 0.15$	V_{OH}

Note: Output test conditions for all other interfaces are determined by the respective standards.

Signal Descriptions

Signal Name		Function	I/O	Description
Power Supplies				
V _{CC}		Power	—	Core Power Supply
V _{CCIO_0} , V _{CCIO_2}		Power	—	Power for I/Os in Bank 0 and 2.
V _{CC_SPI}		Power	—	Power supply for SPI1 ports. For 25-pin WLCSP and 36-pin ucBGA packages, this signal is connected to V _{CCIO_2} .
V _{CCPLL}		Power	—	Power supply for PLL. For 25-pin WLCSP, this is connected internally to V _{CC} .
GND/GNDPLL		GROUND	—	Ground
Configuration				
CRESETB		Configuration	I	Configuration Reset, active LOW. No internal pull-up resistor. Either actively driven externally or connect an 10 kOhm pull-up to V _{CCIO_2} .
CDONE		Configuration	I/O	Configuration Done. Includes a weak pull-up resistor to V _{CCIO_2} .
Config SPI				
Primary	Secondary			
PIOB_xx[HD]	SPI_SCK	Configuration	I/O	This pin is shared with device configuration. During configuration: In Master SPI mode, this pin outputs the clock to external SPI memory. In Slave SPI mode, this pin inputs the clock from external processor.
		General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function [HD]=High Drive I/O.
PIOB_xx[HD]	SPI_SDO	Configuration	Output	This pin is shared with device configuration. During configuration: In Master SPI mode, this pin outputs the command data to external SPI memory. In Slave SPI mode, this pin connects to the MISO pin of the external processor.
		General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function [HD]=High Drive I/O.
PIOB_xx[HD]	SPI_SI	Configuration	Input	This pin is shared with device configuration. During configuration: In Master SPI mode, this pin receives data from external SPI memory. In Slave SPI mode, this pin connects to the MOSI pin of the external processor.
		General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function [HD]=High Drive I/O.

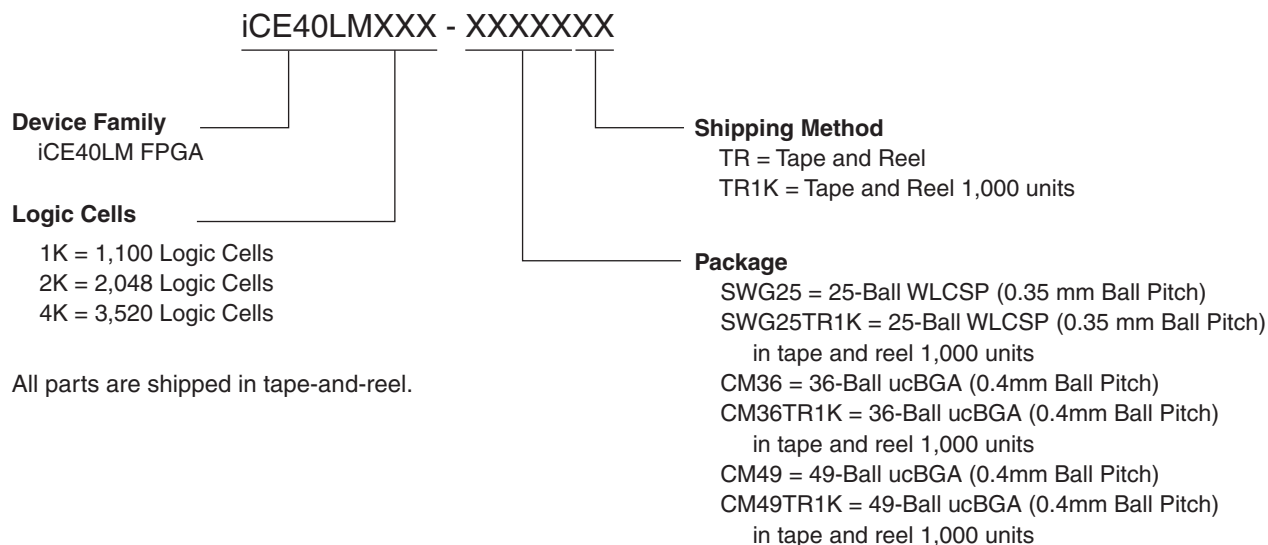
Signal Name		Function	I/O	Description
PIOB_xx[HD]	SPI_SS_B	Configuration	I/O	This pin is shared with device configuration. During configuration: In Master SPI mode, this pin outputs to the external SPI memory. In Slave SPI mode, this pin inputs from the external processor.
		General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function [HD]=High Drive I/O.
Global Signals				
Primary	Secondary			
PIOT_xx	G0	General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function.
		Global	Input	Global input used for high fanout, or clock/reset net. The G0 pin drives the GBUF0 global buffer.
PIOT_xx	G1	General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function.
		Global	Input	Global input used for high fanout, or clock/reset net. The G1 pin drives the GBUF1 global buffer.
PIOT_xx	G3	General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function.
		Global	Input	Global input used for high fanout, or clock/reset net. The G3 pin drives the GBUF3 global buffer.
PIOT_xx	G4	General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function.
		Global	Input	Global input used for high fanout, or clock/reset net. The G4 pin drives the GBUF4 global buffer.
PIOT_xx	G5	General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function.
		Global	Input	Global input used for high fanout, or clock/reset net. The G5 pin drives the GBUF5 global buffer.
PIOB_xx	G6	General I/O	I/O	In user mode, after configuration, this pin can be programmed as general I/O in user function.
		Global	Input	Global input used for high fanout, or clock/reset net. The G6 pin drives the GBUF6 global buffer.
LED Signals				
PIOT_xx		General I/O	I/O	In user mode, with user's choice, this pin can be programmed as I/O in user function in the top (xx = I/O location).
PIOB_xx		General I/O	I/O	In user mode, with user's choice, this pin can be programmed as I/O in user function in the bottom (xx = I/O location) [HD]=High Drive I/O.

Pin Information Summary

Pin Type		iCE40LM-1K			iCE40LM-2K			iCE40LM-4K		
		SWG25	CM36	CM49	SWG25	CM36	CM49	SWG25	CM36	CM49
General Purpose I/O Per Bank	Bank 0	7	15	20	7	15	20	7	15	20
	Bank 2 ¹	11	13	17	11	13	17	11	13	17
Total General Purpose I/Os		18	28	37	18	28	37	18	28	37
Vcc		1	1	2	1	1	2	1	1	2
Vccio	Bank 0	1	1	1	1	1	1	1	1	1
	Bank 2	1	1	1	1	1	1	1	1	1
V _{CC_SPI}		0	0	1	0	0	1	0	0	1
V _{CCPLL}		0	1	1	0	1	1	0	1	1
Miscellaneous Dedicated Pins		2	2	2	2	2	2	2	2	2
GND		2	2	4	2	2	4	2	2	4
NC		0	0	0	0	0	0	0	0	0
Reserved		0	0	0	0	0	0	0	0	0
Total Balls		25	36	49	25	36	49	25	36	49
SPI Interfaces	Bank 0	0	0	0	0	0	0	0	0	0
	Bank 2	1	1	1	2	2	2	2	2	2
I ² C Interfaces	Bank 0	1	1	1	2	2	2	2	2	2
	Bank 2	0	0	0	0	0	0	0	0	0

1. Including General Purpose I/Os powered by V_{CC_SPI} and V_{CCPLL}.

iCE40LM Part Number Description



Ordering Part Numbers

Part Number	LUTs	Supply Voltage	Package	Leads	Temp.
iCE40LM1K-SWG25TR	1100	1.2 V	Halogen-Free caBGA	25	IND
iCE40LM1K-SWG25TR1K	1100	1.2 V	Halogen-Free caBGA	25	IND
iCE40LM1K-CM36TR	1100	1.2 V	Halogen-Free ucBGA	36	IND
iCE40LM1K-CM36TR1K	1100	1.2 V	Halogen-Free ucBGA	36	IND
iCE40LM1K-CM49TR	1100	1.2 V	Halogen-Free ucBGA	49	IND
iCE40LM1K-CM49TR1K	1100	1.2 V	Halogen-Free ucBGA	49	IND
iCE40LM2K-SWG25TR	2048	1.2 V	Halogen-Free caBGA	25	IND
iCE40LM2K-SWG25TR1K	2048	1.2 V	Halogen-Free caBGA	25	IND
iCE40LM2K-CM36TR	2048	1.2 V	Halogen-Free ucBGA	36	IND
iCE40LM2K-CM36TR1K	2048	1.2 V	Halogen-Free ucBGA	36	IND
iCE40LM2K-CM49TR	2048	1.2 V	Halogen-Free ucBGA	49	IND
iCE40LM2K-CM49TR1K	2048	1.2 V	Halogen-Free ucBGA	49	IND
iCE40LM4K-SWG25TR	3520	1.2 V	Halogen-Free caBGA	25	IND
iCE40LM4K-SWG25TR1K	3520	1.2 V	Halogen-Free caBGA	25	IND
iCE40LM4K-CM36TR	3520	1.2 V	Halogen-Free ucBGA	36	IND
iCE40LM4K-CM36TR1K	3520	1.2 V	Halogen-Free ucBGA	36	IND
iCE40LM4K-CM49TR	3520	1.2 V	Halogen-Free ucBGA	49	IND
iCE40LM4K-CM49TR1K	3520	1.2 V	Halogen-Free ucBGA	49	IND

For Further Information

A variety of technical notes for the iCE40 family are available on the Lattice web site.

- TN1248, [iCE40 Programming and Configuration](#)
- TN1274, [iCE40 I2C and SPI Hardened IP Usage Guide](#)
- TN1275, [iCE40LM On-Chip Strobe Generator Usage Guide](#)
- TN1276, [Advanced iCE40 I2C and SPI Hardened IP Usage Guide](#)
- TN1250, [Memory Usage Guide for iCE40 Devices](#)
- TN1251, [iCE40 sysCLOCK PLL Design and Usage Guide](#)
- iCE40LM Pinout Files
- iCE40LM Pin Migration Files
- [Thermal Management](#) document
- [Lattice design tools](#)
- [Schematic Symbols](#)



iCE40LM Family Data Sheet

Revision History

March 2016

Data Sheet DS1045

Date	Version	Section	Change Summary
March 2016	1.6	Architecture	Updated Typical I/O Behavior During Power-up section. Indicated 36-pin ucBGA in package in description.
		DC and Switching Characteristics	Updated Recommended Operating Conditions1 section. Revised footnote 5.
		Pinout Information	Updated Signal Descriptions section. General update of signal names and descriptions.
March 2015	1.5	DC and Switching Characteristics	Updated sysIO Single-Ended DC Electrical Characteristics section. Changed LVCMOS 3.3 and LVCMOS 2.5 V_{OH} Min. (V) from 0.5 to 0.4.
August 2014	1.4	DC and Switching Characteristics	Updated the Recommended Operating Conditions section. Added V_{CC} and V_{CCPLL} information to footnote 1.
			Updated Power Up Sequence section. Revised and added information on required power up sequence.
March 2014	1.3	Ordering Information	Updated Ordering Part Numbers section. Changed packages from csBGA to ucBGA.
	01.2	Architecture	Updated Typical I/O Behavior During Power-up section. Added V_{CCIO_0} to the first statement.
			Updated Power On Reset section. Added V_{CCIO_0} to the first statement.
		Ordering Information	Updated iCE40LM Part Number Description section. Added shipping method and packages.
			Added part numbers in Ordering Part Numbers section.
January 2014	01.1	All	Updated document status from Advance.
		Introduction	Updated device features.
		DC and Switching Characteristics	Updated the following tables: — sysCLOCK PLL Timing – Preliminary — Supply Current — sysCONFIG Port Timing Specifications.
		Pinout Information	Updated SPI and Config SPI Ports information in Signal Descriptions table.
October 2013	01.0	All	General updates for product launch.
		Pinout Information	Updated ball map to 25-pin WLCSP.
September 2013	00.2 EAP	All	General updates to all sections.
August 2013	00.1 EAP	All	Initial release.